

1 Characteristics

Table 2. Absolute maximum ratings

Symbol	Parameter			Value	Unit
$I_{T(RMS)}$	On-state rms current (full sine wave)	D ² PAK, TO-220AB	$T_c = 130\text{ }^{\circ}\text{C}$	12	A
		TO-220AB Ins	$T_c = 120\text{ }^{\circ}\text{C}$		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = $25\text{ }^{\circ}\text{C}$)	F = 50 Hz	t = 20 ms	120	A
		F = 60 Hz	t = 16.7 ms	126	
I^2t	I^2t Value for fusing	$t_p = 10\text{ ms}$		95	A ² s
dI/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \leq 100\text{ ns}$	F = 120 Hz	$T_j = 150\text{ }^{\circ}\text{C}$	50	A/ μ s
V_{DSM}/V_{RSM}	Non repetitive surge peak off-state voltage	$t_p = 10\text{ ms}$	$T_j = 25\text{ }^{\circ}\text{C}$	$V_{DRM}/V_{RRM} + 100$	V
I_{GM}	Peak gate current	$t_p = 20\text{ }\mu\text{s}$	$T_j = 150\text{ }^{\circ}\text{C}$	4	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 150\text{ }^{\circ}\text{C}$	1	W
T_{stg} T_j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 150	$^{\circ}\text{C}$

Table 3. Electrical characteristics ($T_j = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)

Symbol	Test conditions	Quadrant		Value		Unit
				T1235H	T1250H	
$I_{GT}^{(1)}$	$V_D = 12\text{ V}$, $R_L = 33\text{ }\Omega$	I - II - III	MAX.	35	50	mA
V_{GT}		I - II - III	MAX.	1.0		V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3\text{ k}\Omega$	I - II - III	MIN.	0.15		V
$I_H^{(2)}$	$I_T = 500\text{ mA}$		MAX.	35	75	mA
I_L	$I_G = 1.2\text{ }I_{GT}$	I - III	MAX.	50	90	mA
		II		80	110	
dV/dt ⁽²⁾	$V_D = 67\%\text{ }V_{DRM}$, gate open, $T_j = 150\text{ }^{\circ}\text{C}$		MIN.	1000	1500	V/ μ s
(dI/dt) _c ⁽²⁾	Without snubber, $T_j = 150\text{ }^{\circ}\text{C}$		MIN.	16	21	A/ms

1. minimum I_{GT} is guaranteed at 20% of I_{GT} max.

2. for both polarities of A2 referenced to A1.

Table 4. Static characteristics

Symbol	Test conditions			Value	Unit
$V_T^{(1)}$	$I_{TM} = 17\text{ A}$, $t_p = 380\text{ }\mu\text{s}$	$T_j = 25\text{ }^\circ\text{C}$	MAX.	1.5	V
$V_{t0}^{(1)}$	Threshold voltage	$T_j = 150\text{ }^\circ\text{C}$	MAX.	0.80	V
$R_d^{(1)}$	Dynamic resistance	$T_j = 150\text{ }^\circ\text{C}$	MAX.	30	m Ω
I_{DRM} $I_{RRM}^{(2)}$	$V_{DRM} = V_{RRM}$	$T_j = 25\text{ }^\circ\text{C}$	MAX.	5	μA
		$T_j = 150\text{ }^\circ\text{C}$	MAX.	3.9	mA
	$V_D/V_R = 400\text{ V}$ (at peak mains voltage)	$T_j = 150\text{ }^\circ\text{C}$	MAX.	3.2	
	$V_D/V_R = 200\text{ V}$ (at peak mains voltage)	$T_j = 150\text{ }^\circ\text{C}$	MAX.	2.7	

1. for both polarities of A2 referenced to A1

2. $t_p = 380\text{ }\mu\text{s}$ **Table 5. Thermal resistance**

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	D ² PAK / TO-220AB	1.4	$^\circ\text{C/W}$
		TO-220AB Ins	3.3	
$R_{th(j-a)}$	Junction to ambient	$S = 1\text{ cm}^2$ D ² PAK	45	
		TO-220AB / TO-220AB Ins	60	

Figure 1. Maximum power dissipation versus on-state rms current (full cycle)

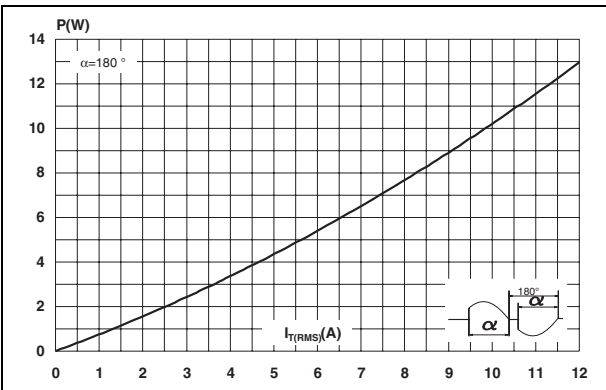


Figure 2. On-state rms current versus case temperature (full cycle)

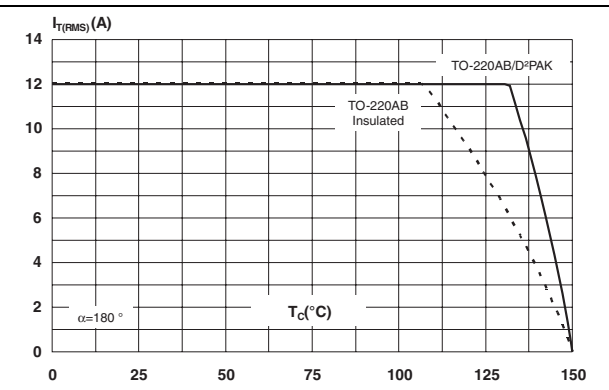


Figure 3. On-state rms current versus ambient temperature

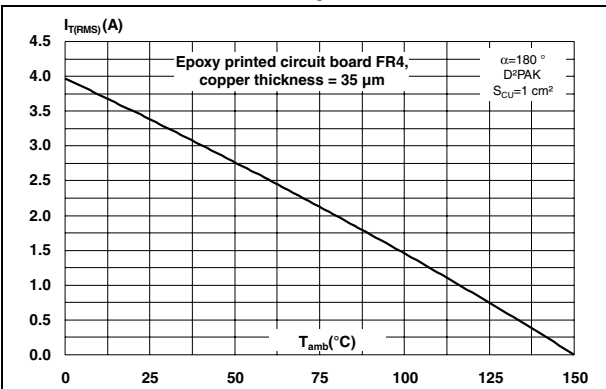


Figure 4. Variation of thermal impedance versus pulse duration

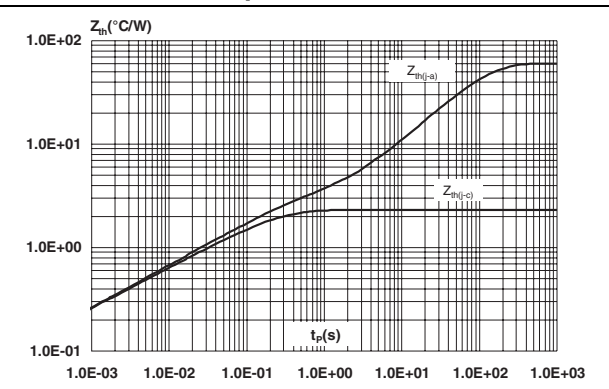


Figure 5. On-state characteristics (maximum values)

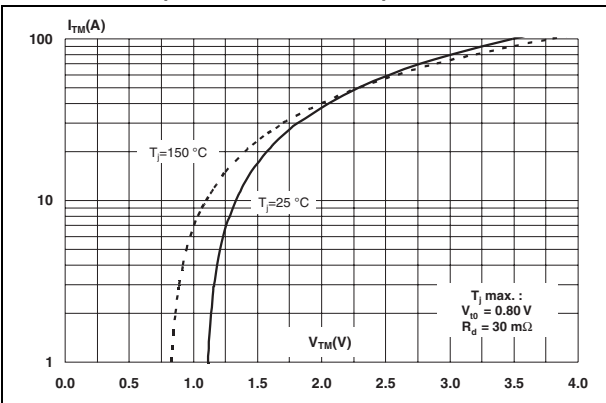


Figure 6. Surge peak on-state current versus number of cycles

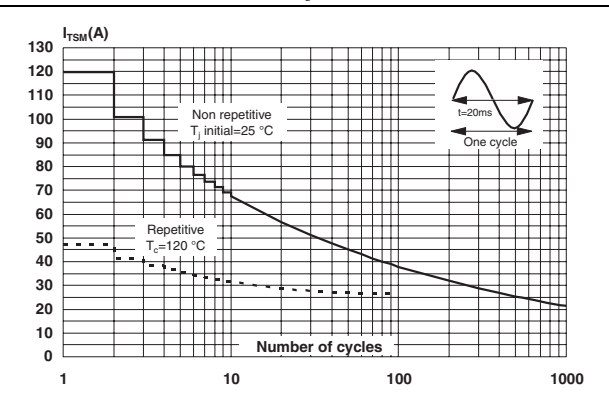


Figure 7. Non-repetitive surge peak on-state current for a sinusoidal pulse with

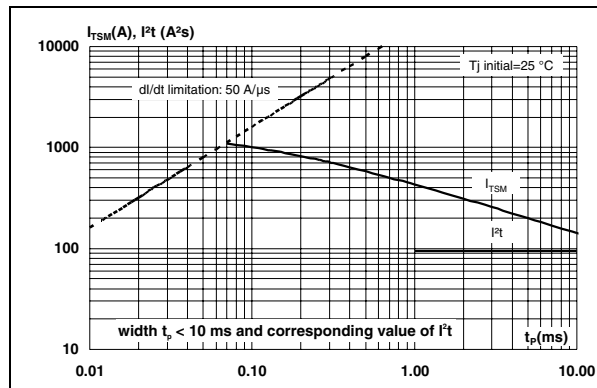


Figure 8. Relative variation of I_{GT}, I_H, I_L vs junction temperature (typical values)

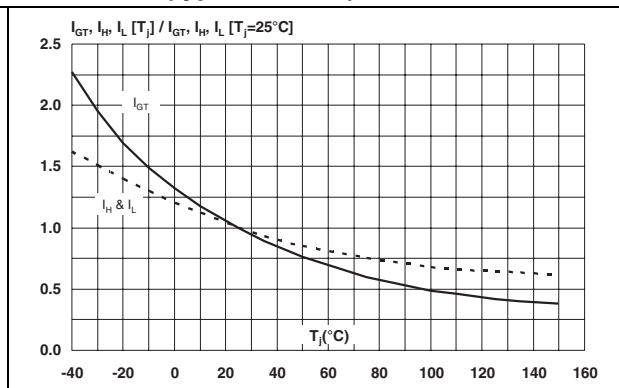


Figure 9. Relative variation of critical rate of decrease of main current $(dI/dt)_c$ versus reapplied $(dV/dt)_c$

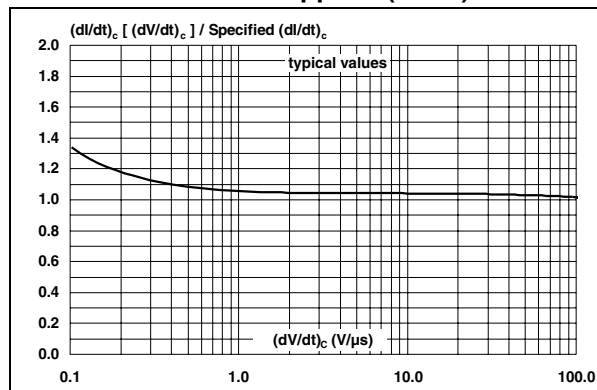


Figure 10. Relative variation of critical rate of decrease of main current versus junction temperature

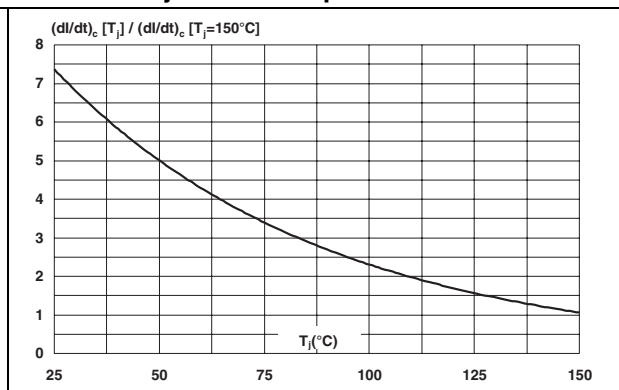


Figure 11. Leakage current versus junction temperature for different values of blocking voltage (typical values)

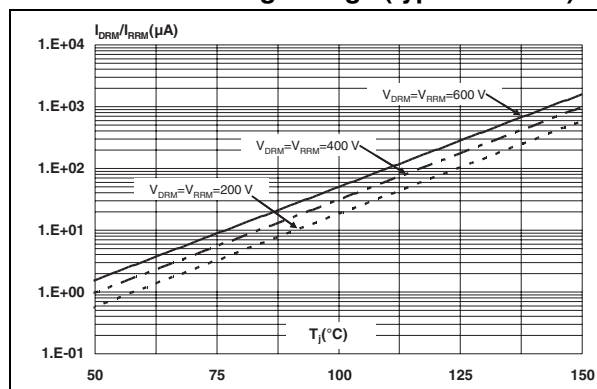
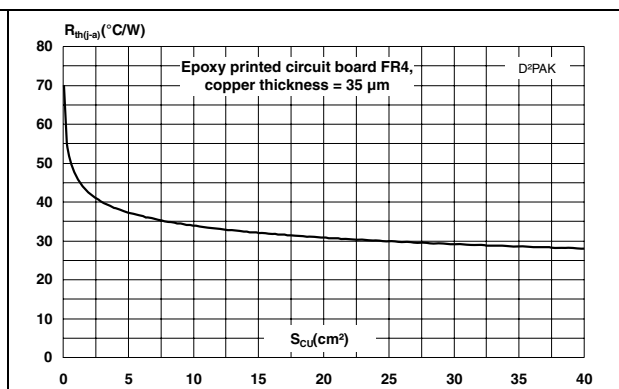
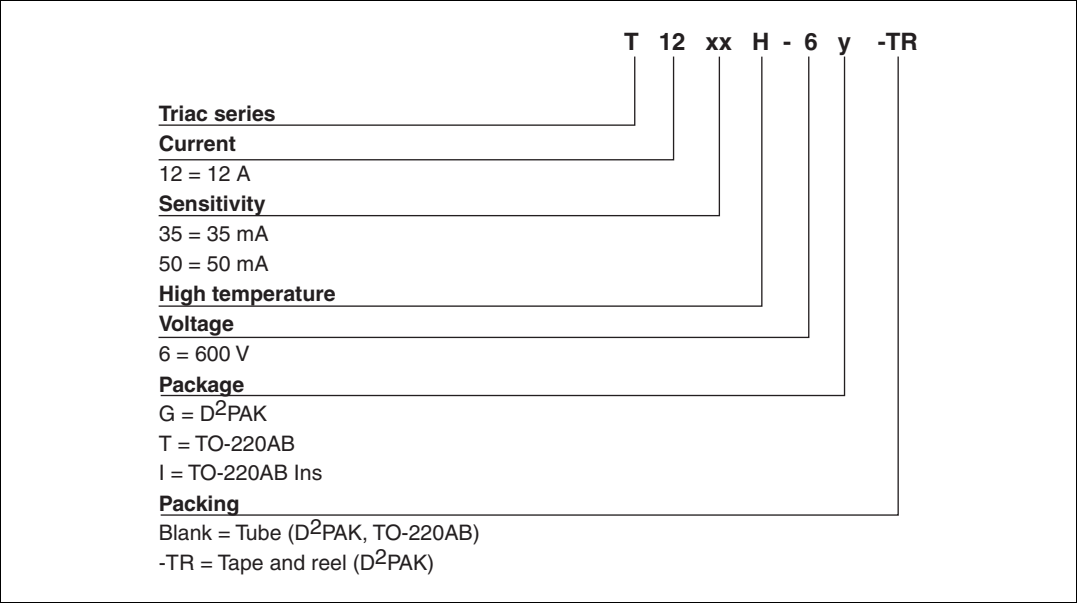


Figure 12. Variation of thermal resistance junction to ambient versus copper surface under tab



2 Ordering information scheme

Figure 13. Ordering information scheme



3 Package information

- Epoxy meets UL94, V0
- Recommended torque 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 6. D²PAK dimensions

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.169		0.181
A1	2.49		2.69	0.098		0.106
A2	0.03		0.23	0.001		0.009
B	0.70		0.93	0.027		0.037
B2	1.25	1.40		0.048	0.055	
C	0.45		0.60	0.017		0.024
C2	1.21		1.36	0.047		0.054
D	8.95		9.35	0.352		0.368
E	10.00		10.28	0.393		0.405
G	4.88		5.28	0.192		0.208
L	15.00		15.85	0.590		0.624
L2	1.27		1.40	0.050		0.055
L3	1.40		1.75	0.055		0.069
R	0.40			0.016		
V2	0°		8°	0°		8°

Figure 14. Footprint (dimensions in mm)

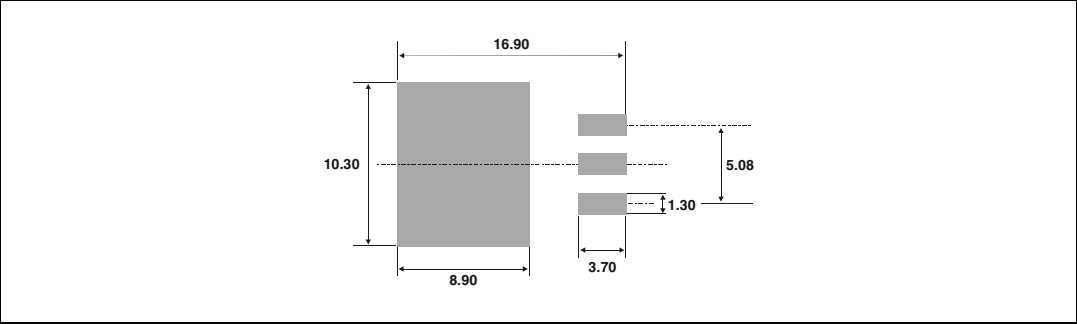


Table 7. TO-220AB and TO-220AB Ins dimensions

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
ØI	3.75		3.85	0.147		0.151
l4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
l2	1.14		1.70	0.044		0.066
l3	1.14		1.70	0.044		0.066
M		2.60			0.102	

4 Ordering information

Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
T12xxH-6G	T12xxH 6G	D ² PAK	1.5 g	50	Tube
T12xxH-6G-TR	T12xxH 6G	D ² PAK	1.5 g	1000	Tape and reel
T12xxH-6T	T12xxH 6T	TO-220AB	2.3 g	50	Tube
T12xxH-6I	T12xxH 6I	TO-220AB Ins	2.3 g	50	Tube

5 Revision history

Table 9. Document revision history

Date	Revision	Changes
17-Apr-2007	1	First issue.
20-Sep-2011	2	Updated: Features , Description and Figure 2 .

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